

ZWS10B

EVALUATION DATA

型式データ

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使用記号 Terminology used

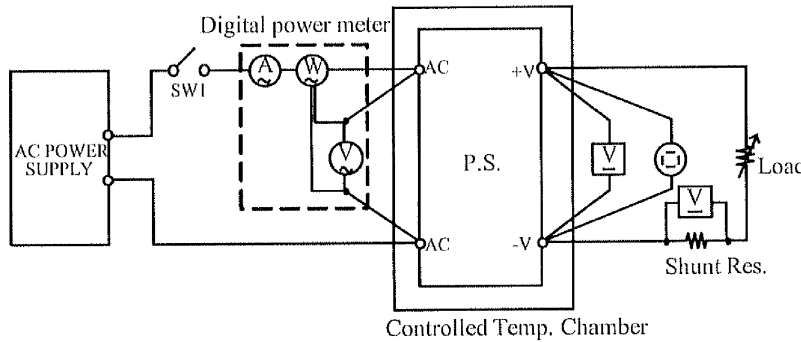
	定義	Definition
V _{in} 入力電圧	Input voltage
V _{out} 出力電圧	Output voltage
I _{in} 入力電流	Input current
I _{out} 出力電流	Output current
T _a 周囲温度	Ambient temperature
f 周波数	Frequency

1. 測定方法 Evaluation Method

1.1 測定回路 Circuit used for determination

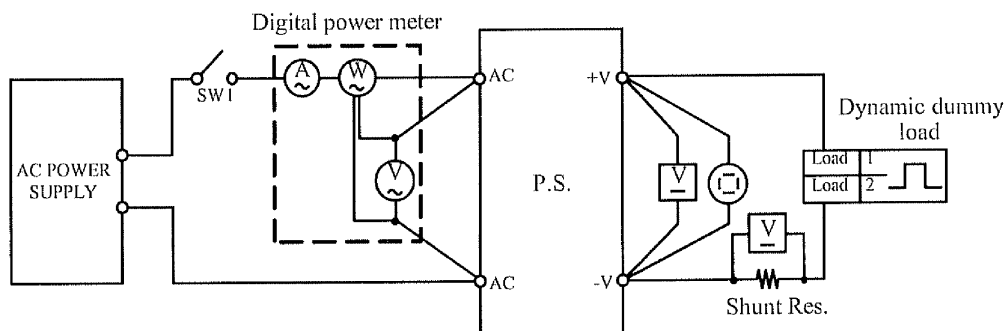
測定回路1 Circuit 1 used for determination

- ・ 静特性 Steady state data
- ・ 過電流保護特性 Over current protection (OCP) characteristics
- ・ 過電圧保護特性 Over voltage protection (OVP) characteristics
- ・ 出力立ち上がり特性 Output rise characteristics
- ・ 出力立ち下がり特性 Output fall characteristics
- ・ 出力保持時間特性 Hold up time characteristics

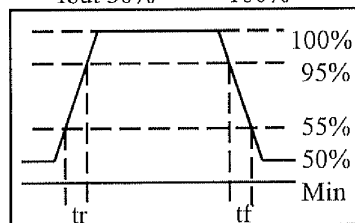


測定回路2 Circuit 2 used for determination

- ・ 過渡応答(負荷急変)特性 Dynamic load response characteristics

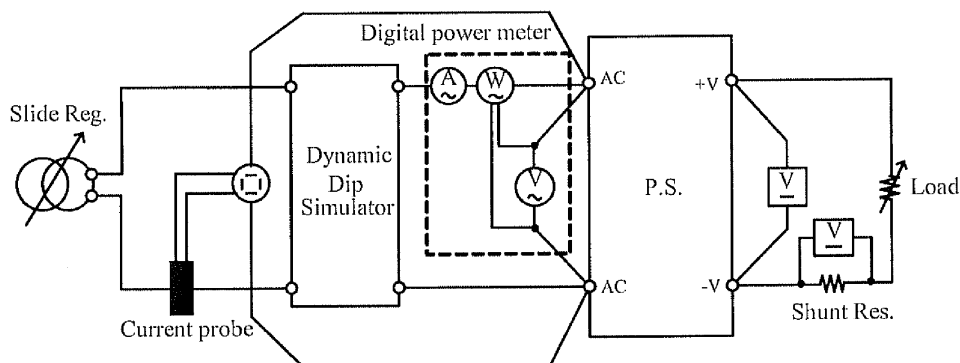


Output current waveform
Iout 50% <=> 100%



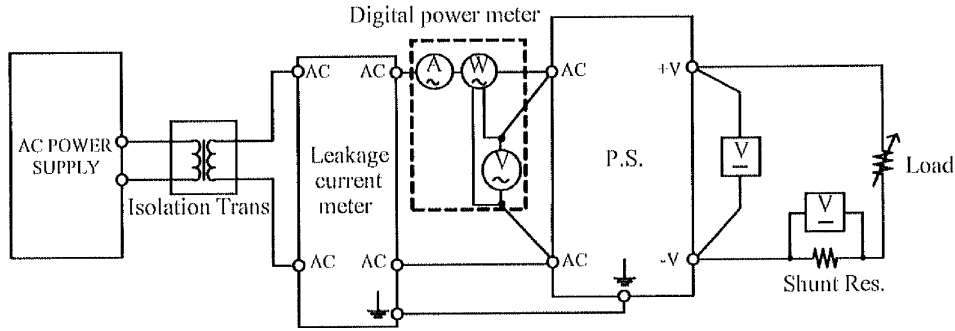
測定回路3 Circuit 3 used for determination

- ・ 入力サージ電流(突入電流)波形 Inrush current waveform



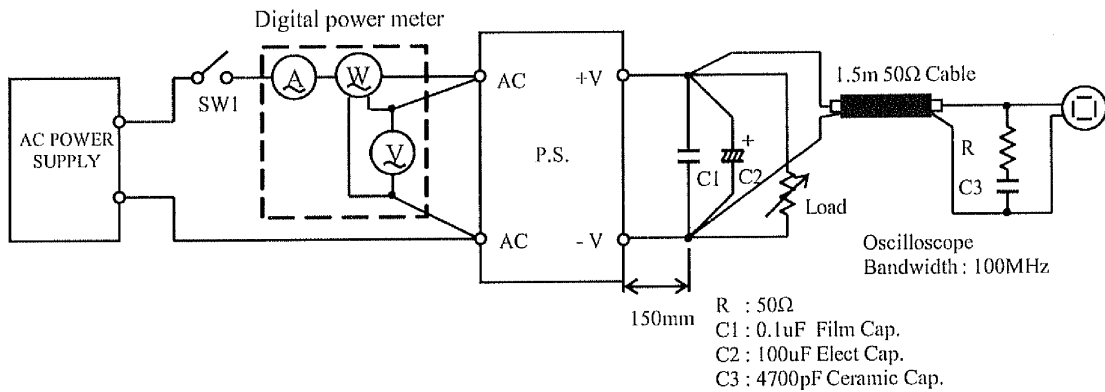
測定回路4 Circuit 4 used for determination

- ・リーク電流特性 Leakage current characteristics



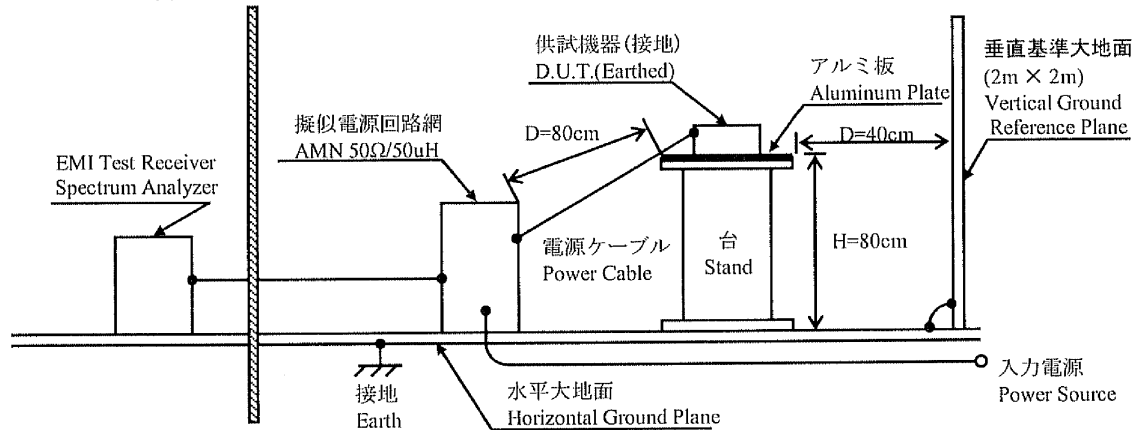
測定回路5 Circuit 5 used for determination

- ・出力リップル、ノイズ波形 Output ripple and noise waveform

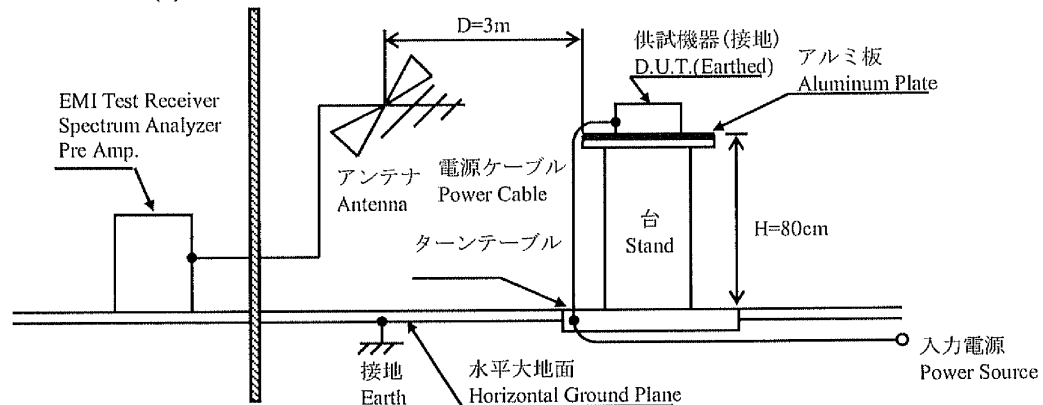


測定構成 Configuration used for determination

- ・EMI特性 Electro-Magnetic Interference characteristics
- (a) 雑音端子電圧 (帰還ノイズ) Conducted Emission



- (b) 雑音電界強度 (放射ノイズ) Radiated Emission



1.2 使用測定機器 List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	DIGITAL STORAGE OSCILLOSCOPE	TEKTRONIX	TDS 540A
2	DIGITAL STORAGE OSCILLOSCOPE	YOKOGAWA ELECT.	DL1720E
3	DIGITAL MULTIMETER	FLUKE	45
4	DIGITAL POWER METER	YOKOGAWA ELECT.	WT210
5	CURRENT PROBE	TEKTRONIX	63202
6	DC AMPERE METER	TEKTRONIX	P5100
7	DYNAMIC DUMMY LOAD	CHROMA	63030
8	CVCF	KIKUSUI	PCR2000L
9	LEAKAGE CURRENT METER	SIMPSON	228
10	CONTROLLED TEMP. CHAMBER	TABAI-ESPEC	63203
11	EMI TEST RECEIVER	ROHDE & SCHWARZ	ESCI-03
12	LISN	ROHDE & SCHWARZ	ENV216
13	BICONICAL ANTENNA	EMCO	63208

2.1 静特性 Steady state data

(1) 入力・負荷・温度変動／出力起動・遮断電圧

Regulation - line and load, Temperature drift / Start up voltage and Drop out voltage

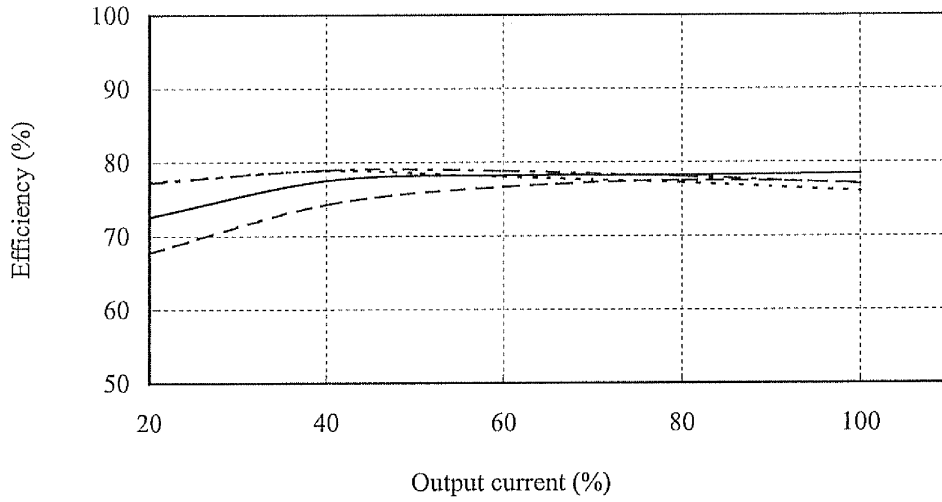
5V		1. Regulation - line and load				Condition Ta : 25 °C	
Iout \ Vin	85VAC	100VAC	200VAC	265VAC	line regulation		
0%	5.028V	5.028V	5.028V	5.028V	0mV	0.000%	
50%	5.027V	5.027V	5.026V	5.026V	1mV	0.020%	
100%	5.024V	5.024V	5.024V	5.024V	0mV	0.000%	
load	4mV	4mV	4mV	4mV			
regulation	0.080%	0.080%	0.080%	0.080%			
		2. Temperature drift				Conditions Vin : 100 VAC Iout : 100 %	
Ta	-10°C	+25°C	+50°C	temperature stability			
Vout	5.032V	5.024V	5.018V	14mV	0.280%		
		3. Start up voltage and Drop out voltage				Conditions Ta : 25 °C Iout : 100 %	
Start up voltage (Vin)		45VAC					
Drop out voltage (Vin)		44VAC					
12V		1. Regulation - line and load				Condition Ta : 25 °C	
Iout \ Vin	85VAC	100VAC	200VAC	265VAC	line regulation		
0%	12.010V	12.010V	12.010V	12.010V	0mV	0.000%	
50%	12.009V	12.009V	12.009V	12.009V	0mV	0.000%	
100%	12.007V	12.007V	12.007V	12.007V	0mV	0.000%	
load	3mV	3mV	3mV	3mV			
regulation	0.025%	0.025%	0.025%	0.025%			
		2. Temperature drift				Conditions Vin : 100 VAC Iout : 100 %	
Ta	-10°C	+25°C	+50°C	temperature stability			
Vout	12.016V	12.007V	12.001V	15mV	0.125%		
		3. Start up voltage and Drop out voltage				Conditions Ta : 25 °C Iout : 100 %	
Start up voltage (Vin)		45VAC					
Drop out voltage (Vin)		44VAC					
24V		1. Regulation - line and load				Condition Ta : 25 °C	
Iout \ Vin	85VAC	100VAC	200VAC	265VAC	line regulation		
0%	24.063V	24.063V	24.063V	24.063V	0mV	0.000%	
50%	24.060V	24.060V	24.060V	24.060V	0mV	0.000%	
100%	24.057V	24.057V	24.057V	24.057V	0mV	0.000%	
load	6mV	6mV	6mV	6mV			
regulation	0.025%	0.025%	0.025%	0.025%			
		2. Temperature drift				Conditions Vin : 100 VAC Iout : 100 %	
Ta	-10°C	+25°C	+50°C	temperature stability			
Vout	24.088V	24.057V	24.025V	63mV	0.263%		
		3. Start up voltage and Drop out voltage				Conditions Ta : 25 °C Iout : 100 %	
Start up voltage (Vin)		51VAC					
Drop out voltage (Vin)		48VAC					

(2) 効率対出力電流

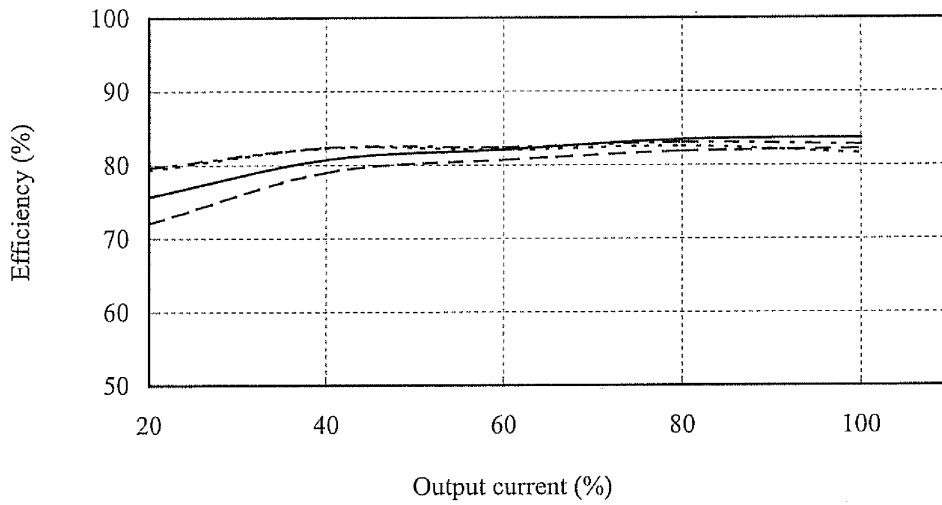
Efficiency vs. Output current

Conditions Vin : 85 VAC -----
 : 100 VAC -.-.-.-
 : 200 VAC ————
 : 265 VAC -.-.-.-
 Ta : 25 °C

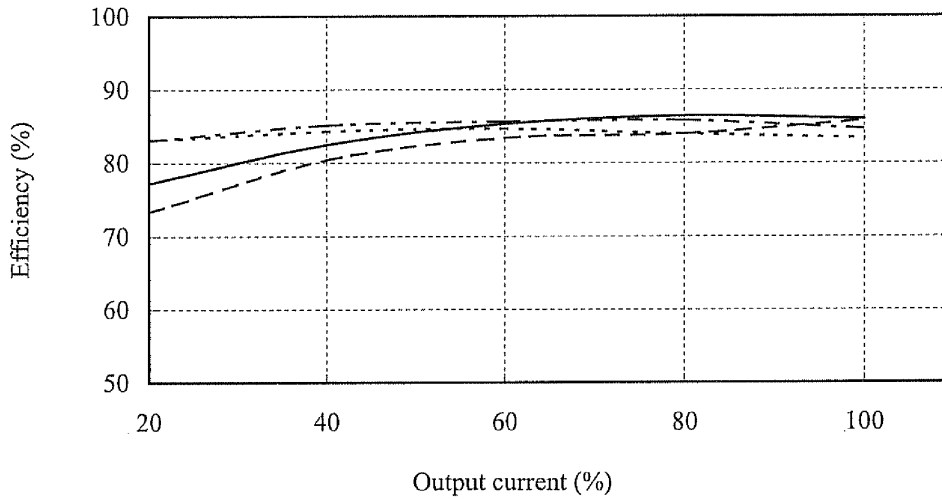
5V



12V



24V



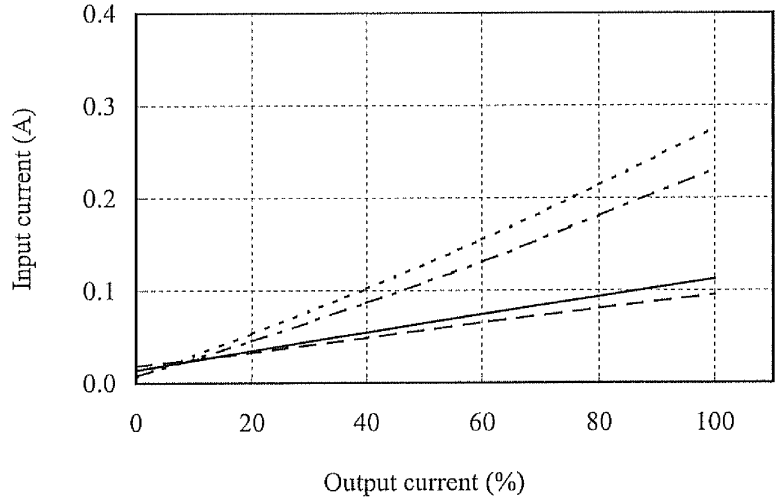
(3) 入力電流対出力電流
Input current vs. Output current

Conditions Vin : 85 VAC -----
: 100 VAC -.-.-.-
: 200 VAC _____
: 265 VAC -.-.-.-
Ta : 25 °C

5V

Io: 0%

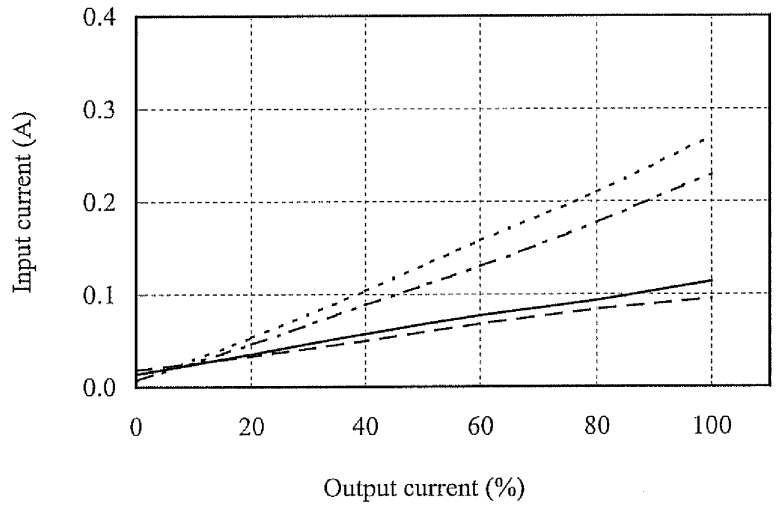
Vin	Input current
85VAC	0.006A
100VAC	0.007A
200VAC	0.014A
265VAC	0.018A



12V

Io: 0%

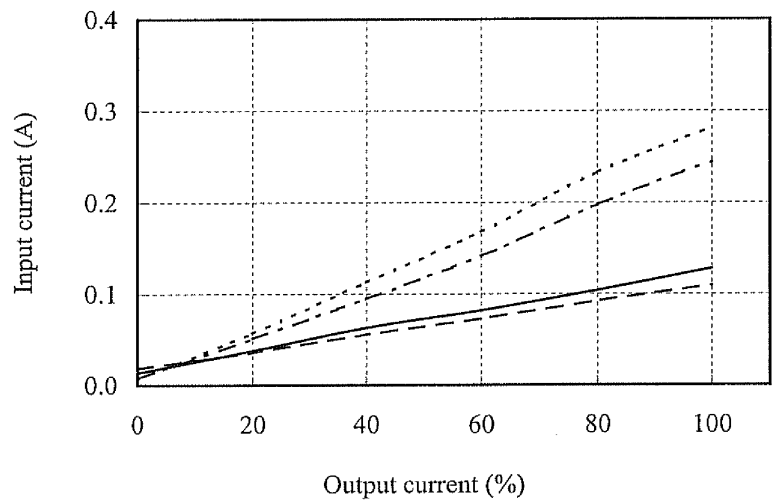
Vin	Input current
85VAC	0.006A
100VAC	0.007A
200VAC	0.014A
265VAC	0.018A



24V

Io: 0%

Vin	Input current
85VAC	0.007A
100VAC	0.007A
200VAC	0.014A
265VAC	0.018A



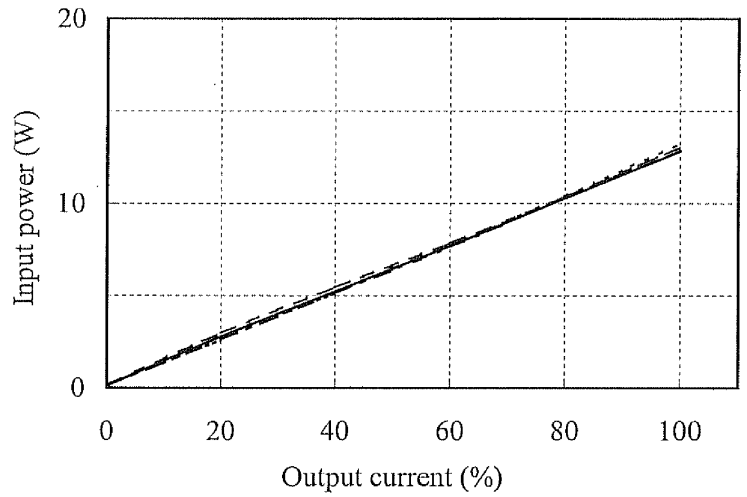
(4) 入力電力対出力電流
Input power vs. Output current

Conditions Vin : 85 VAC -----
 : 100 VAC - - - -
 : 200 VAC ————
 : 265 VAC - - - -
 Ta : 25 °C

5V

Io: 0%

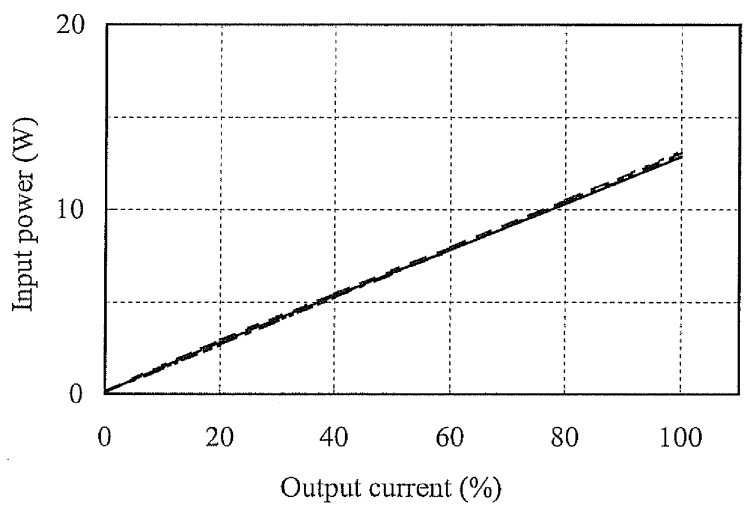
Vin	Input power
85VAC	0.08W
100VAC	0.08W
200VAC	0.12W
265VAC	0.15W



12V

Io: 0%

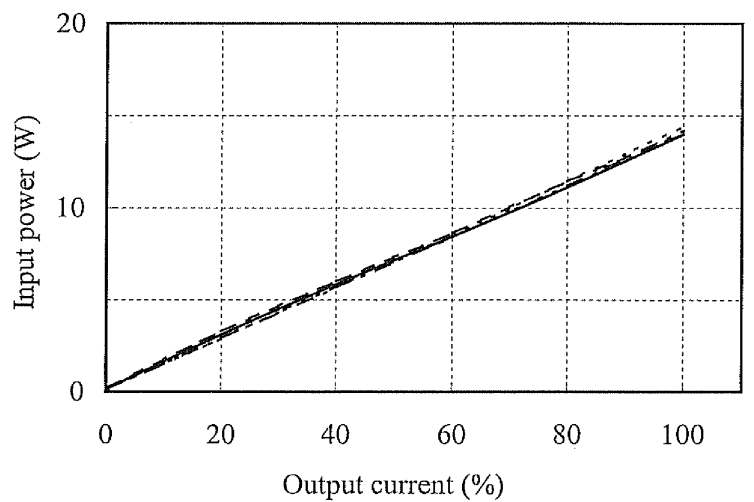
Vin	Input power
85VAC	0.06W
100VAC	0.06W
200VAC	0.10W
265VAC	0.14W



24V

Io: 0%

Vin	Input power
85VAC	0.09W
100VAC	0.10W
200VAC	0.14W
265VAC	0.18W



2.2 過電流保護特性

Over current protection (OCP) characteristics

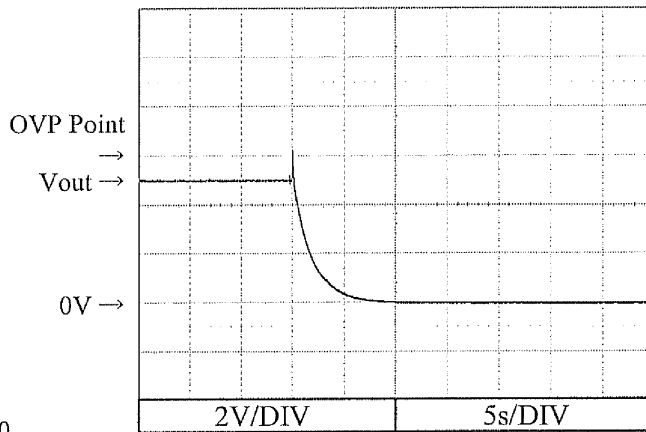
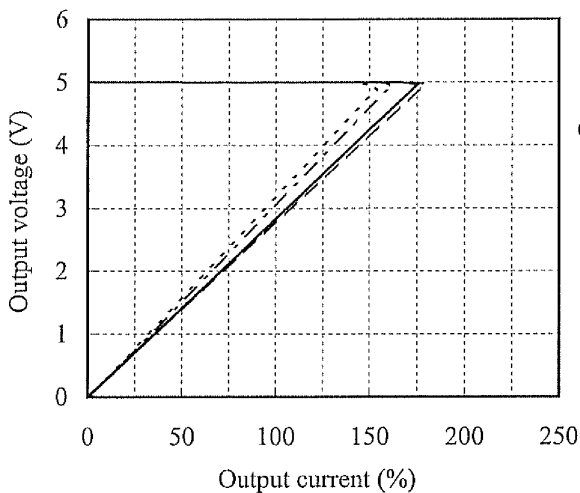
2.3 過電壓保護特性

Over voltage protection (OVP) characteristics

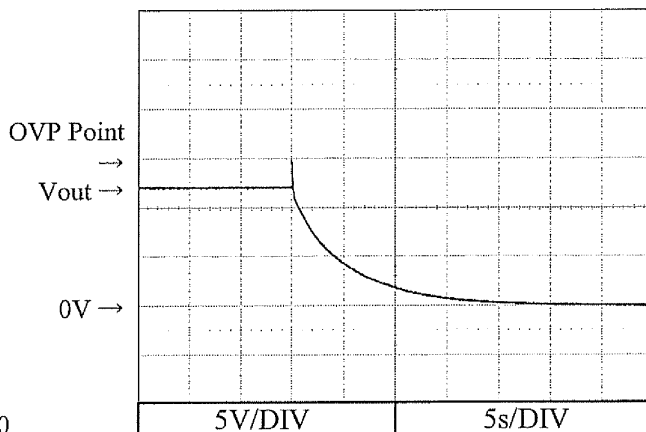
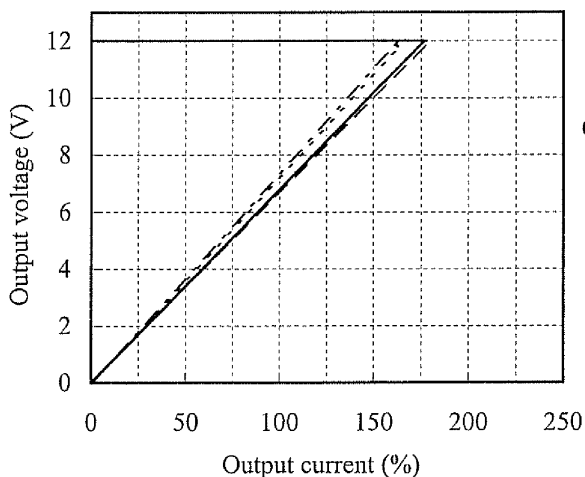
Conditions Vin : 85 VAC -----
 100 VAC - - - - -
 200 VAC ————
 265 VAC - - - - -
 Ta : 25 °C

Conditions Vin : 100 VAC
 Iout : 0 %
 Ta : 25 °C

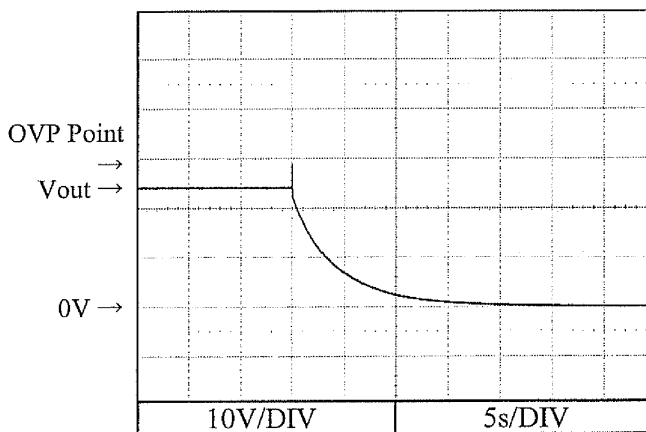
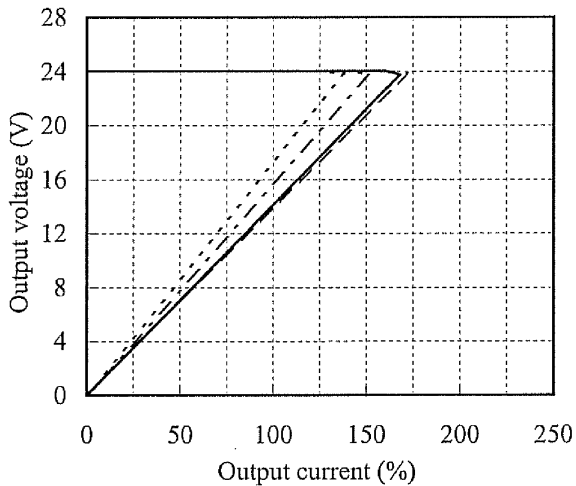
5V



12V



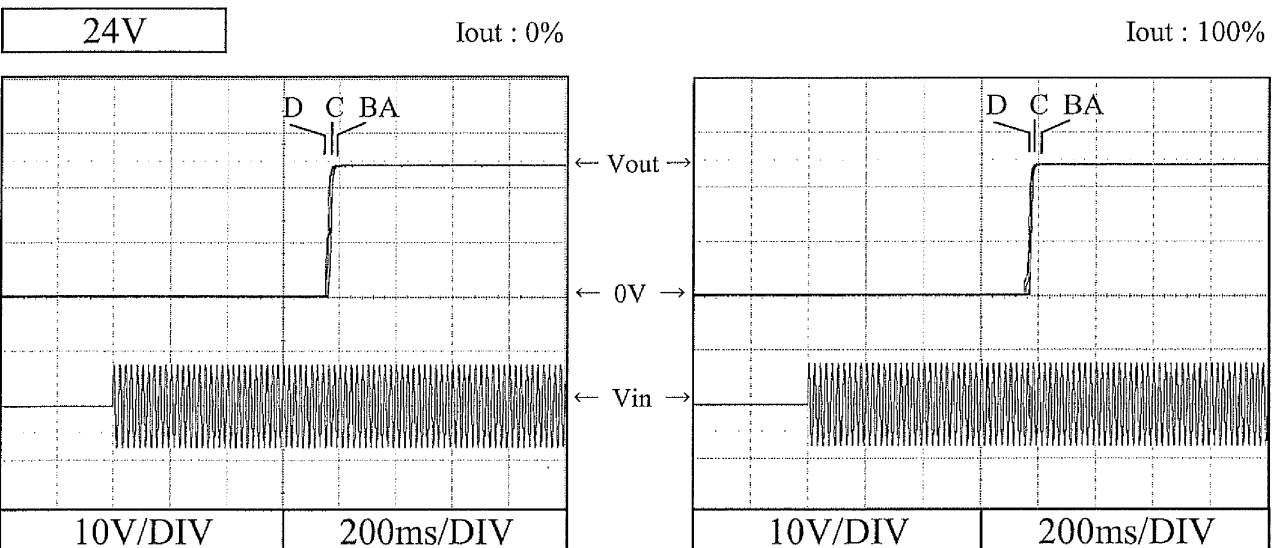
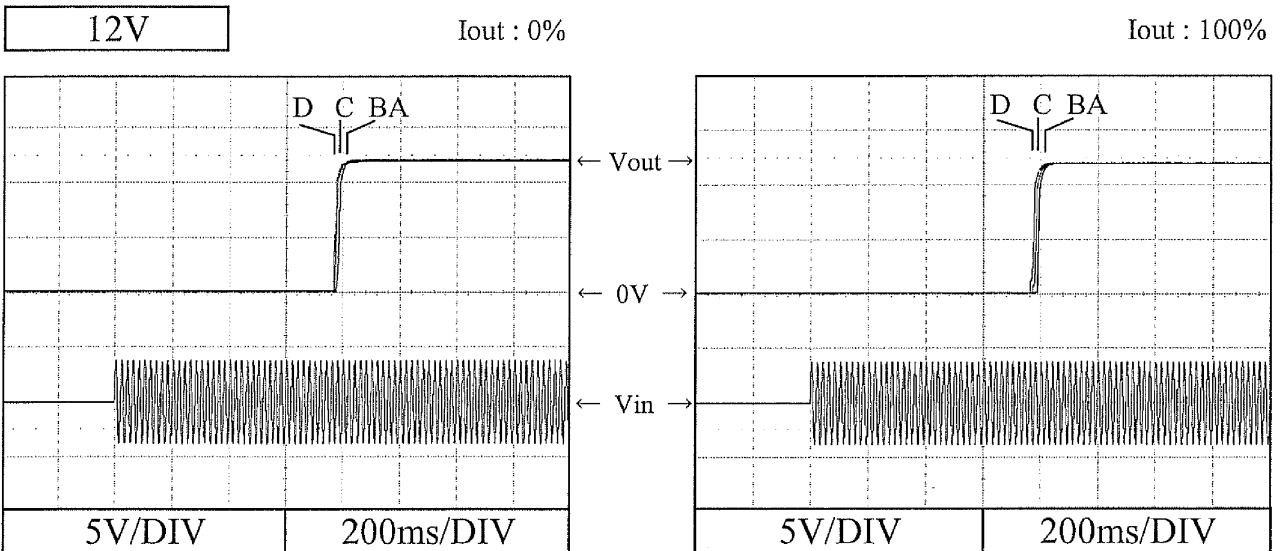
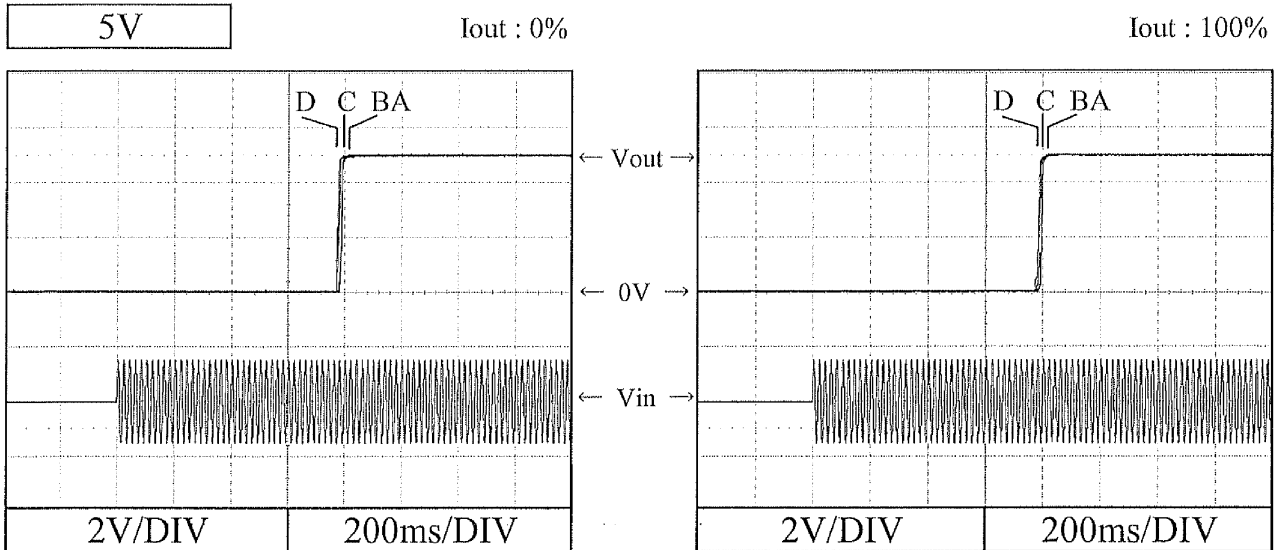
24V



2.4 出力立ち上がり特性

Output rise characteristics

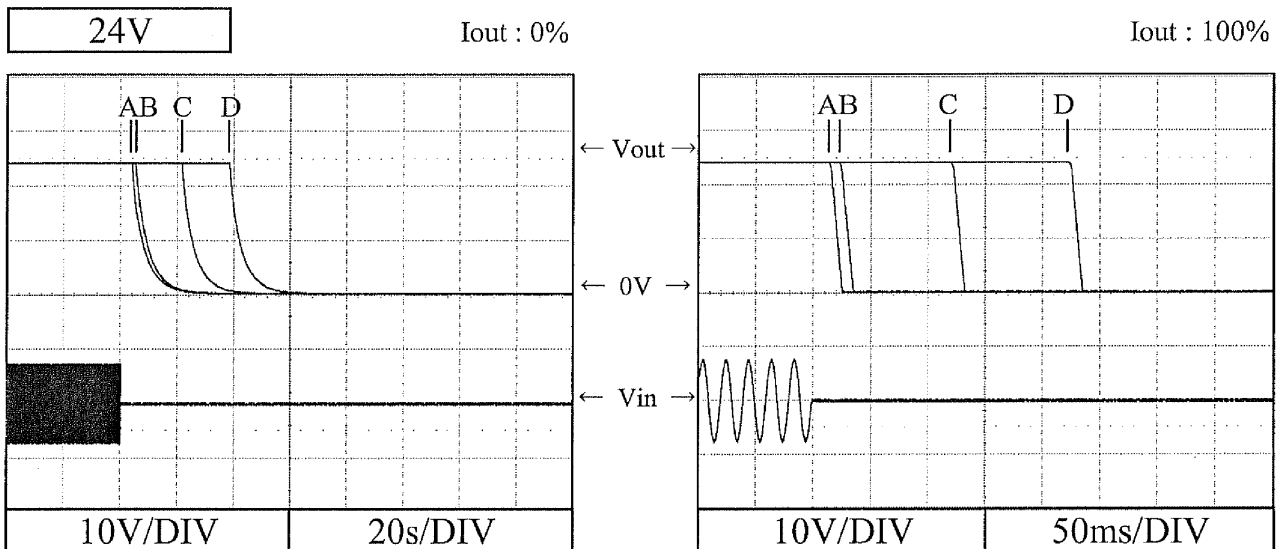
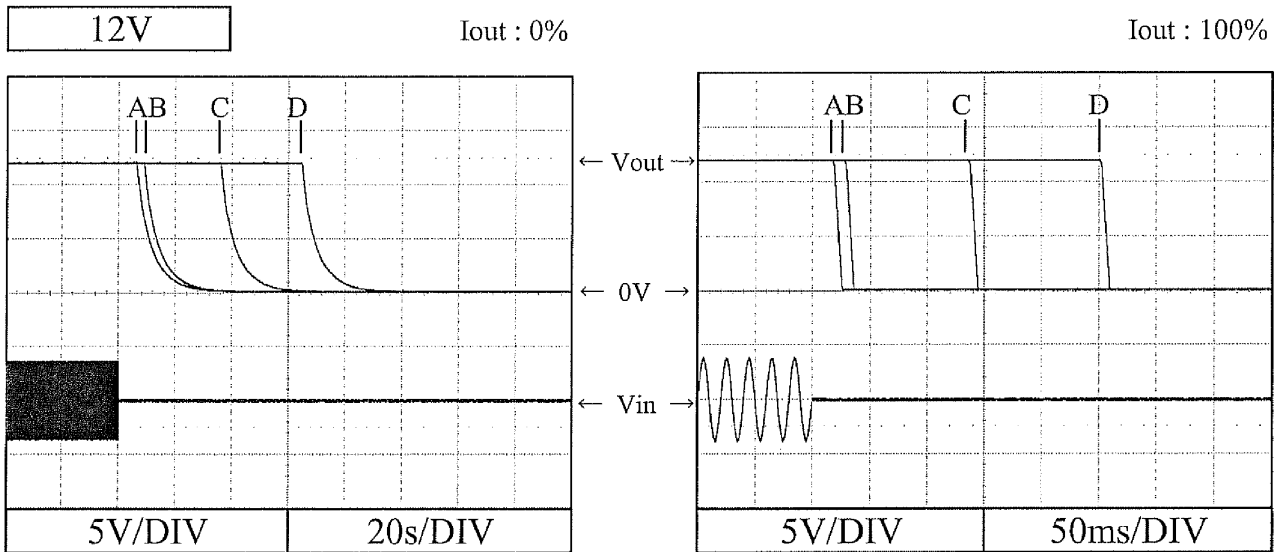
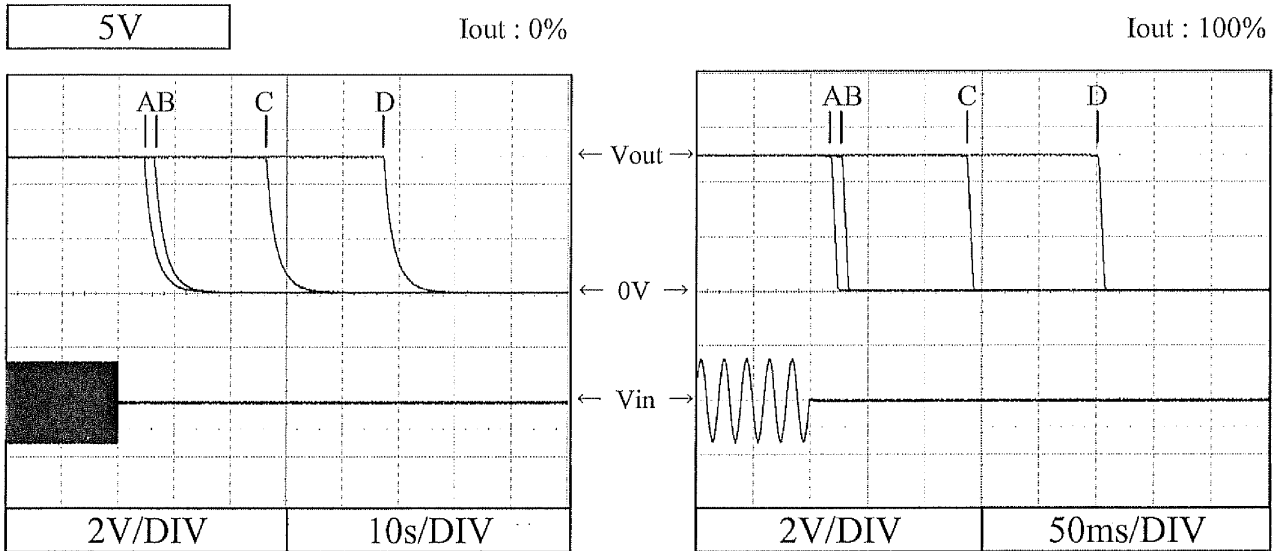
Conditions Vin : 85 VAC (A)
 100 VAC (B)
 200 VAC (C)
 265 VAC (D)
 Ta : 25 °C



2.5 出力立ち下がり特性

Output fall characteristics

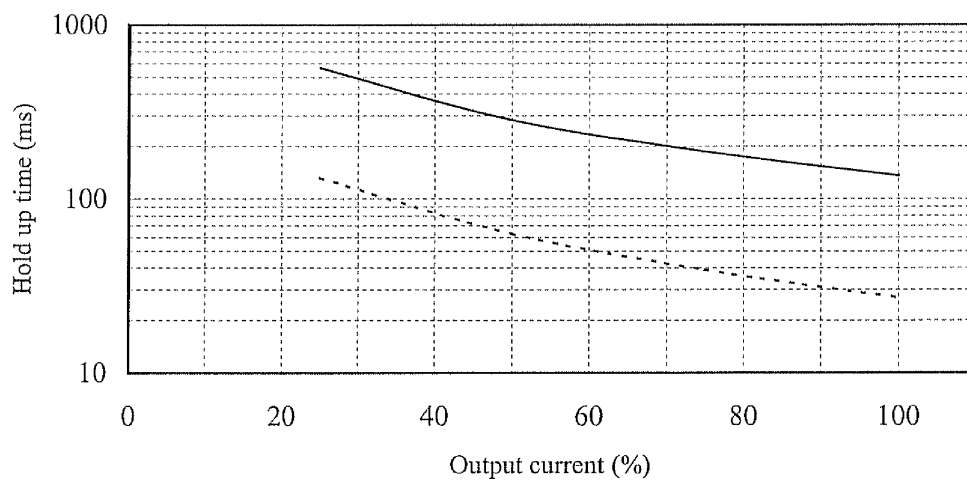
Conditions Vin : 85 VAC (A)
 100 VAC (B)
 200 VAC (C)
 265 VAC (D)
 Ta : 25 °C



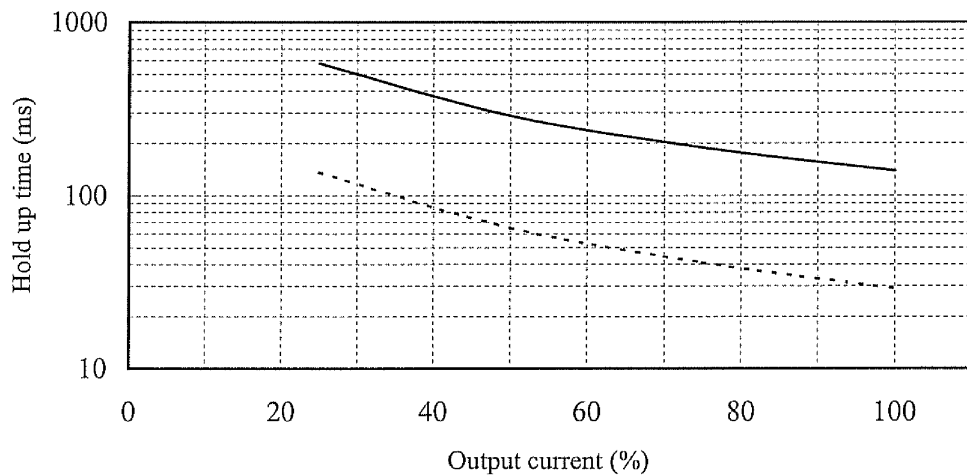
2.6 出力保持時間特性
Hold up time characteristics

Conditions Vin : 100 VAC -----
200 VAC ————
Ta : 25 °C

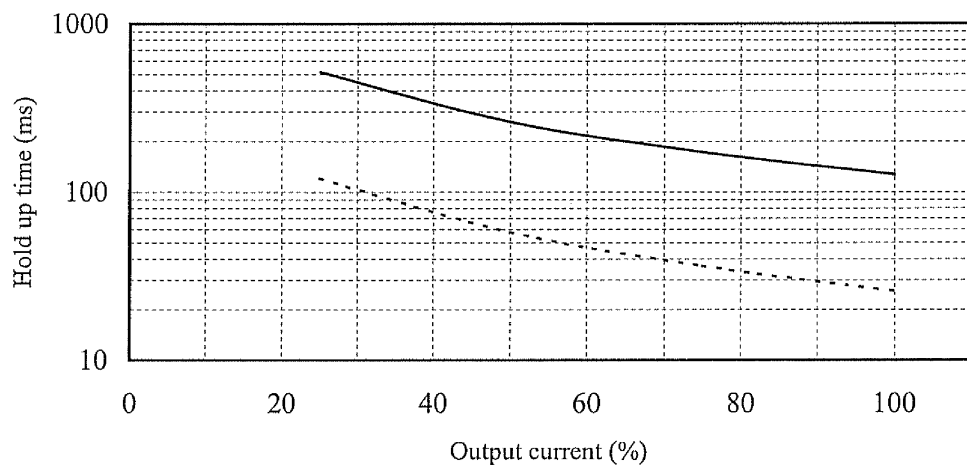
5V



12V



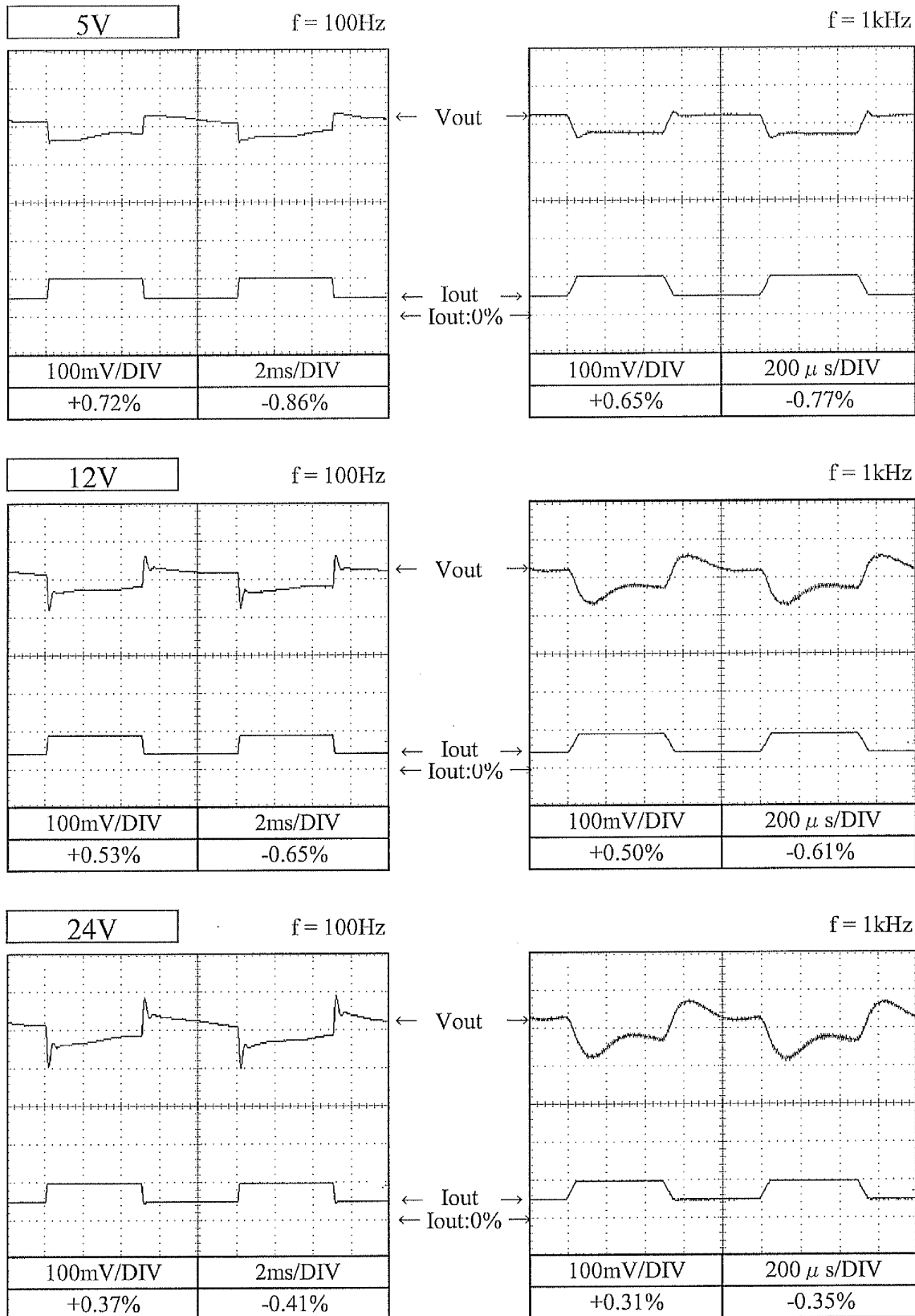
24V



2.7 過渡応答 (負荷急変) 特性

Dynamic load response characteristics

Conditions Vin: 100 VAC
 Iout: 50 % ↔ 100 %
 (tr = tf = 50us)
 Ta: 25 °C



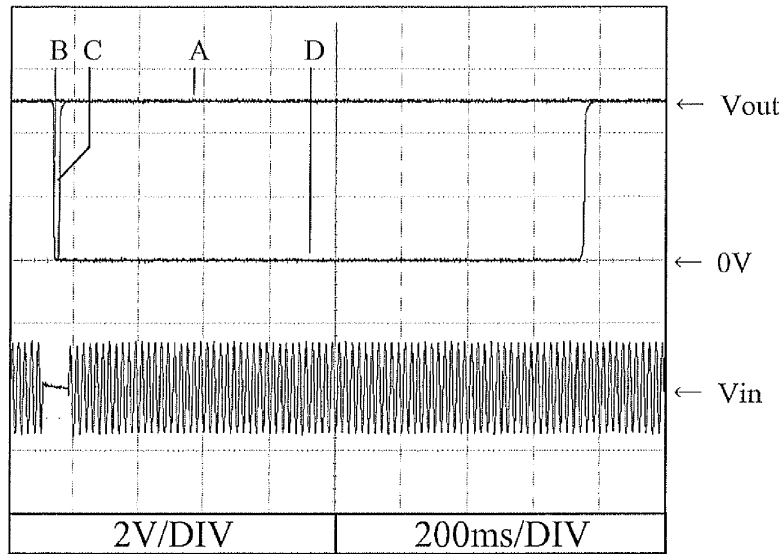
2.8 入力電圧瞬停特性

Response to brown out characteristics

Conditions Vin : 100 VAC
Iout : 100 %
Ta : 25 °C

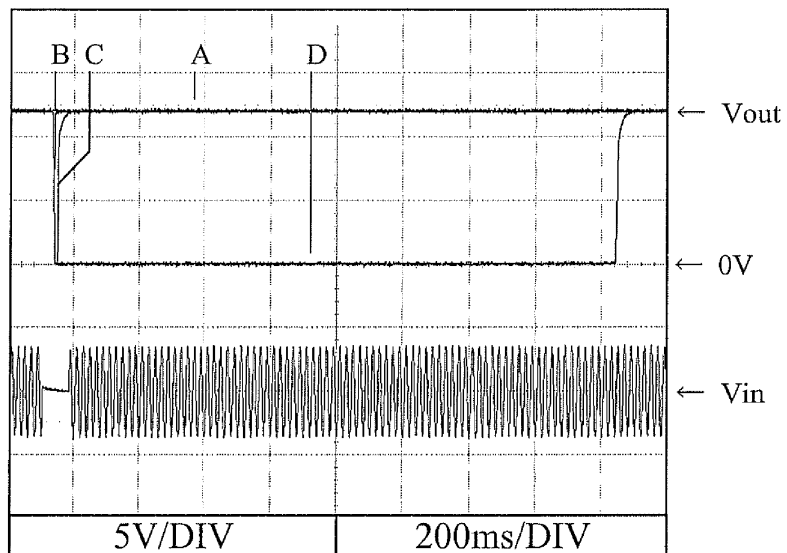
5V

A = 23ms
B = 31ms
C = 48ms
D = 80ms



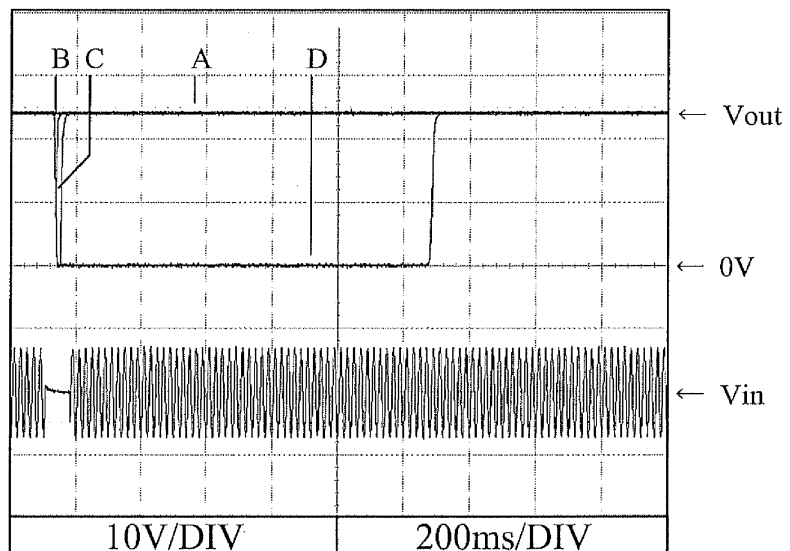
12V

A = 24ms
B = 33ms
C = 44ms
D = 83ms



24V

A = 22ms
B = 30ms
C = 46ms
D = 78ms



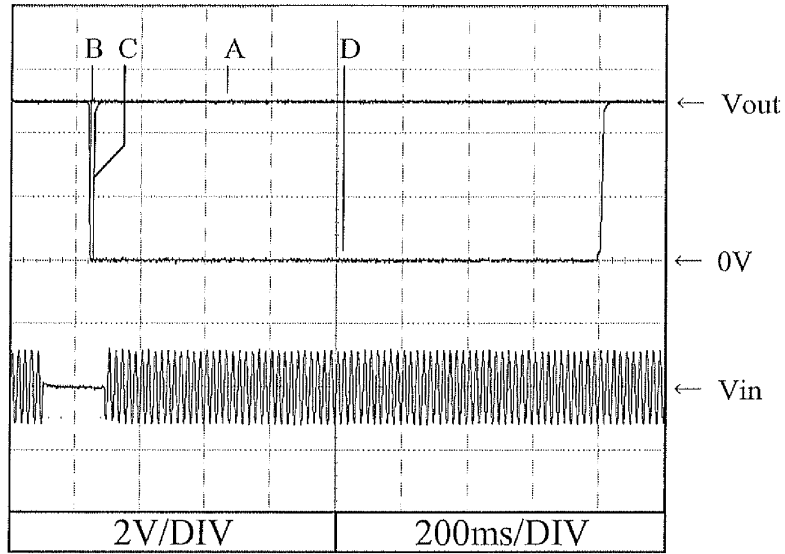
2.8 入力電圧瞬停特性

Response to brown out characteristics

Conditions Vin : 200 VAC
Iout : 100 %
Ta : 25 °C

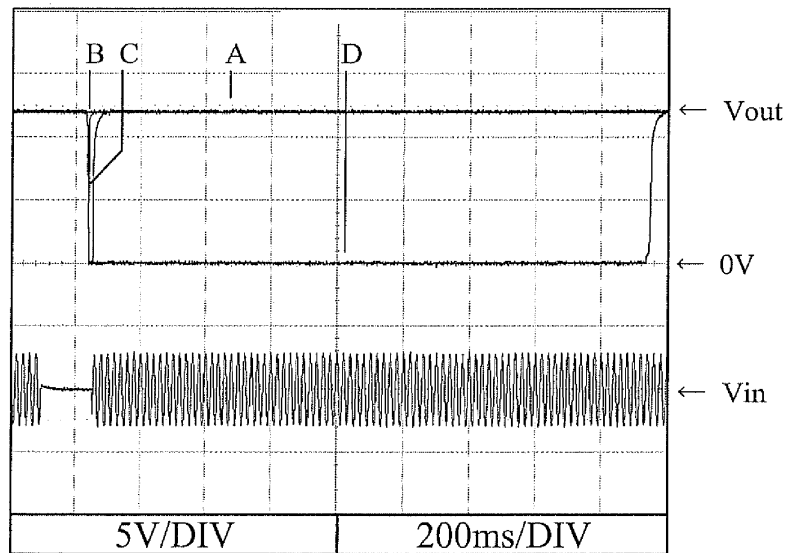
5V

A = 136ms
B = 142ms
C = 154ms
D = 192ms



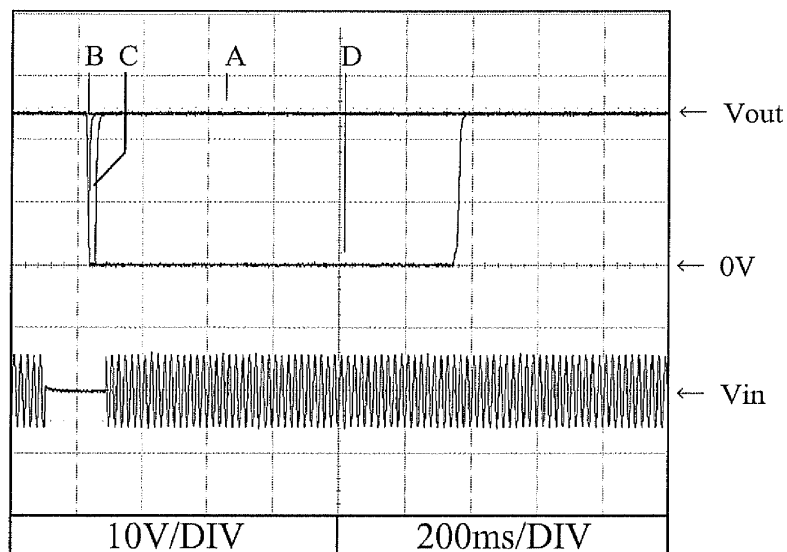
12V

A = 135ms
B = 145ms
C = 158ms
D = 190ms



24V

A = 122ms
B = 131ms
C = 152ms
D = 186ms

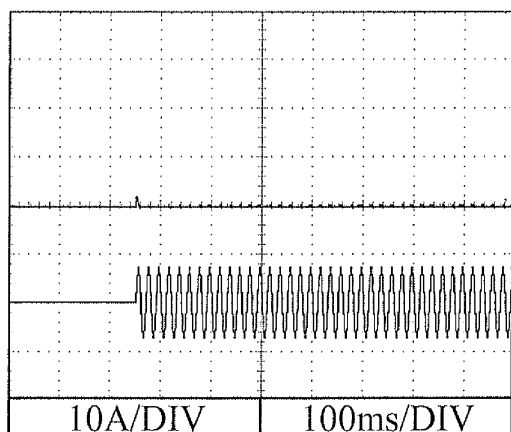


2.9 入力サージ電流 (突入電流) 波形
Inrush current waveform

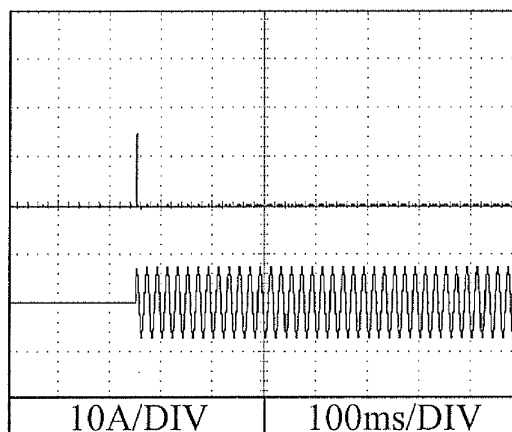
5V

Conditions V_{in} : 100 VAC
 I_{out} : 100 %
 T_a : 25 °C

Switch on phase angle of input AC voltage
 $\phi = 0^\circ$

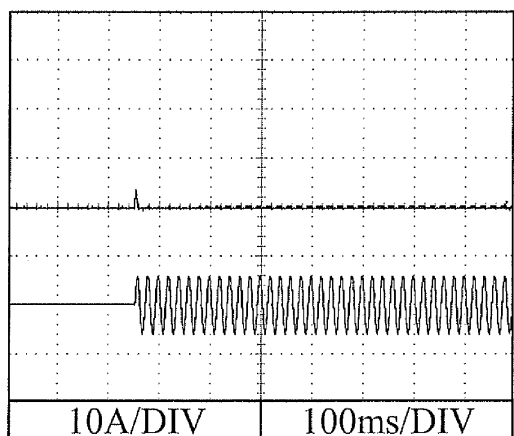


Switch on phase angle of input AC voltage
 $\phi = 90^\circ$

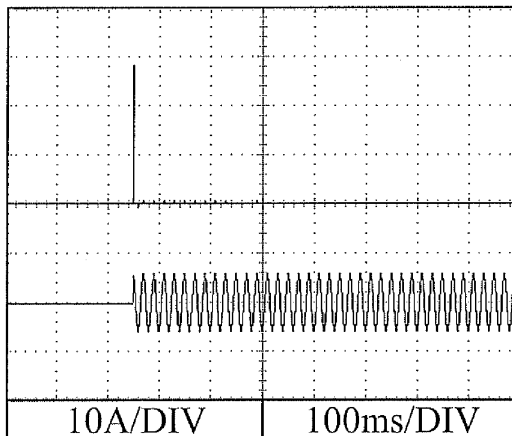


Conditions V_{in} : 200 VAC
 I_{out} : 100 %
 T_a : 25 °C

Switch on phase angle of input AC voltage
 $\phi = 0^\circ$



Switch on phase angle of input AC voltage
 $\phi = 90^\circ$

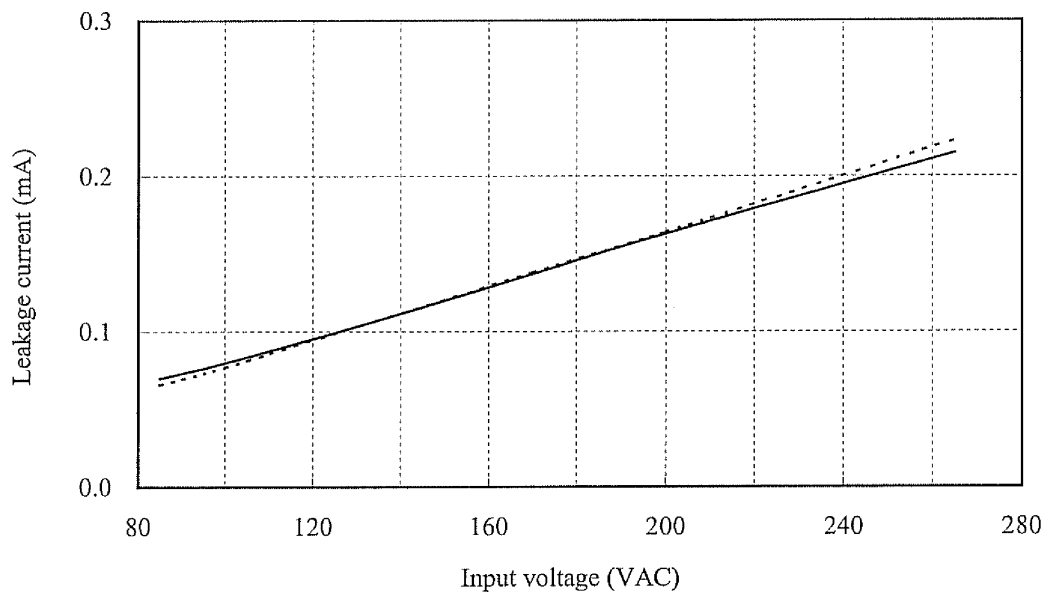


2.10 リーク電流特性
Leakage current characteristics

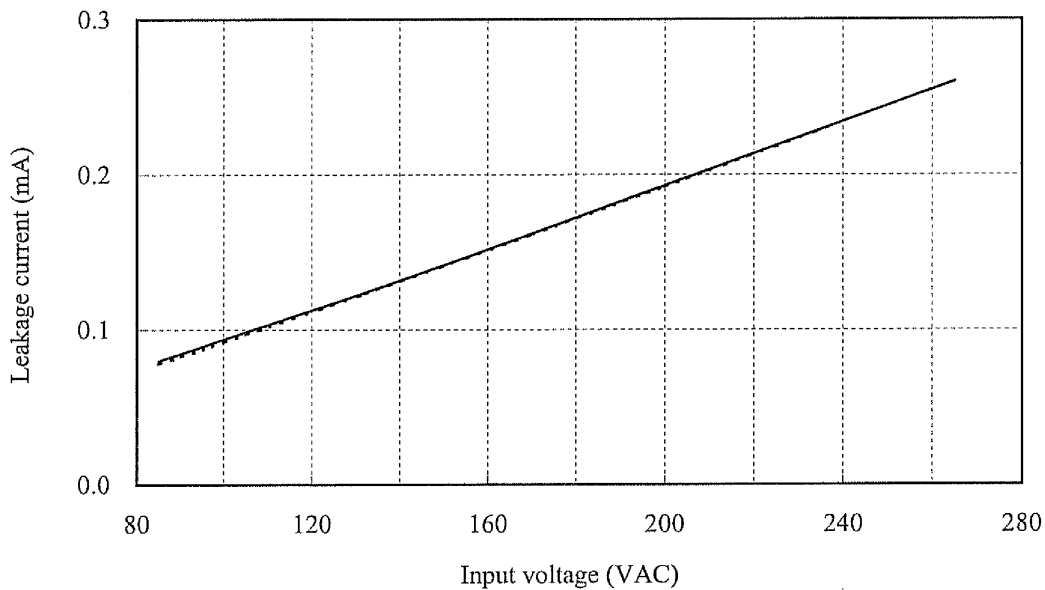
Conditions Iout : 0 % -----
 100 % ——
 Ta : 25 °C
Equipment used : 228 (Simpson)

5V

f : 50 Hz

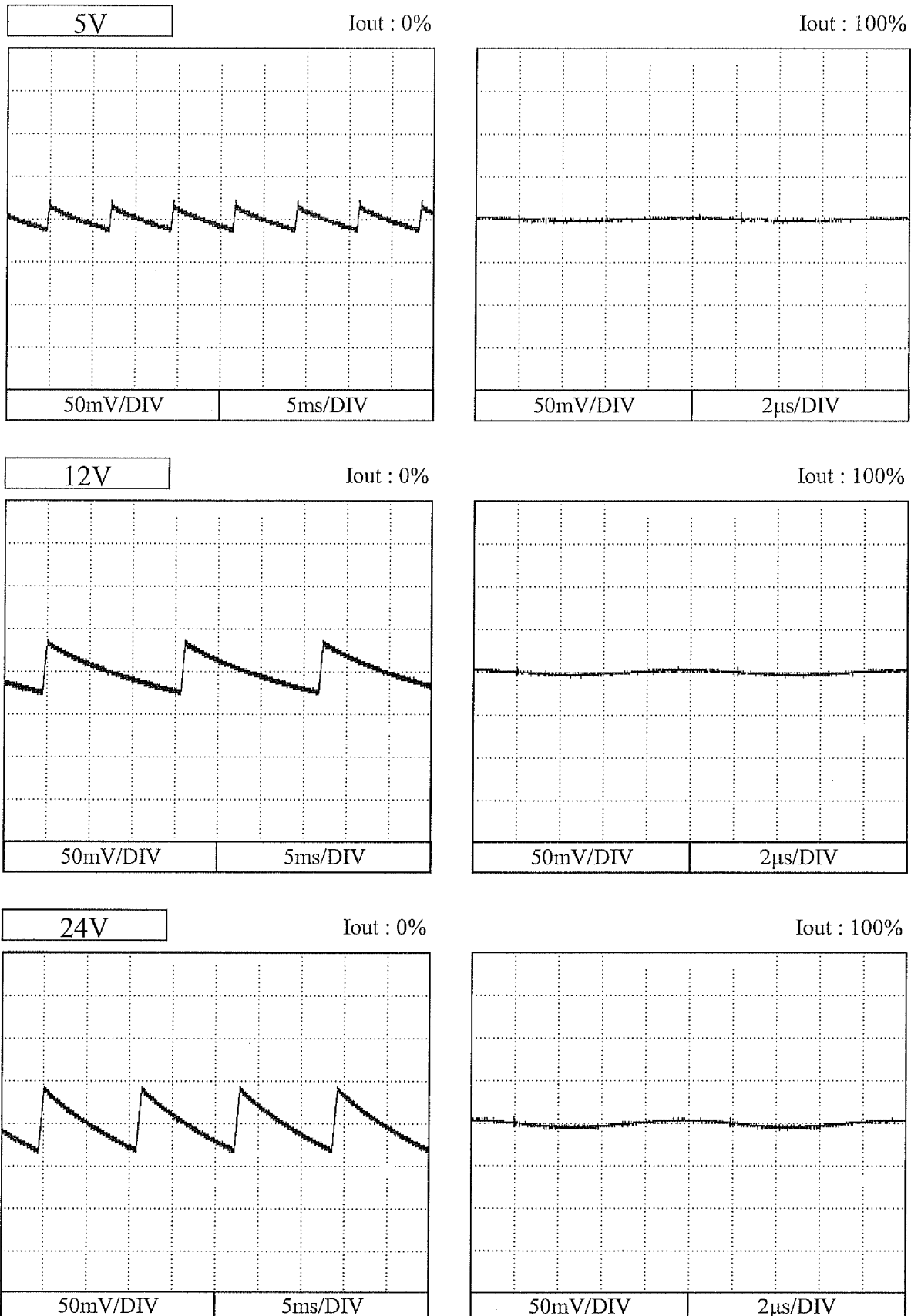


f : 60 Hz



2.11 出力リップル、ノイズ波形
Output ripple and noise waveform

Conditions Vin : 100 VAC
Ta : 25 °C



2.12 EMI 特性

Electro-Magnetic Interference characteristics

ZWS10B

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

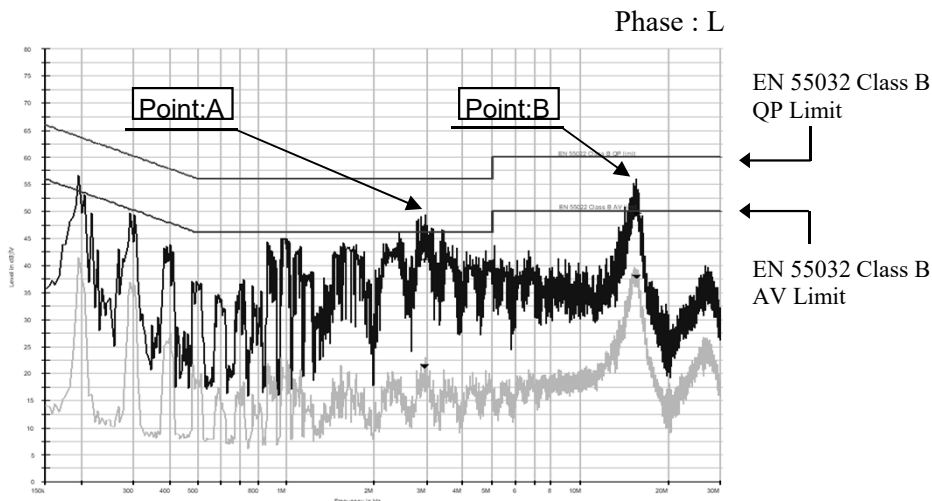
雑音端子電圧

Conducted Emission

5V

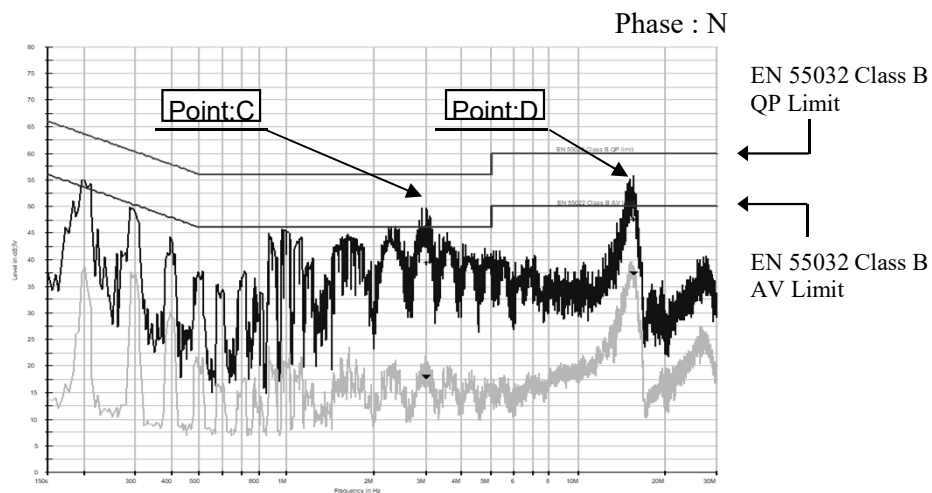
Point A (2.961MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	56.0	41.1
AV	46.0	21.4

Point B (15.558MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	60.0	49.6
AV	50.0	37.9



Point C (3.001MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	56.0	39.4
AV	46.0	17.8

Point D (15.604MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	60.0	47.6
AV	50.0	37.4



EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ
Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

ZWS10B

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

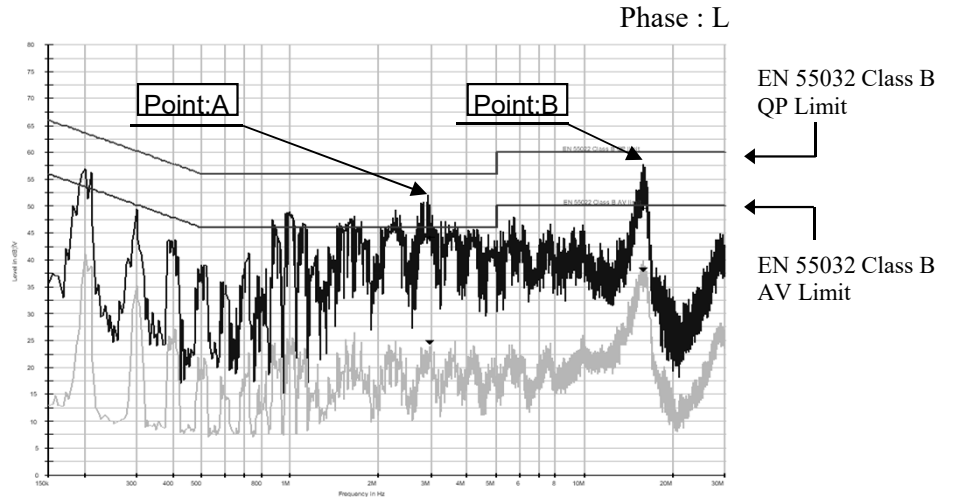
雑音端子電圧

Conducted Emission

12V

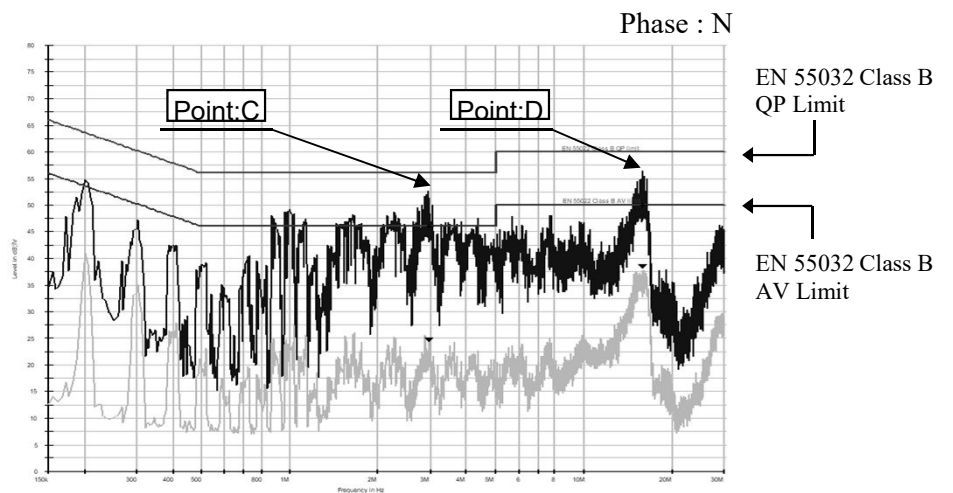
Point A (2.994MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	56.0	44.1
AV	46.0	24.6

Point B (15.923MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	60.0	49.7
AV	50.0	38.2



Point C (2.995MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	56.0	46.0
AV	46.0	24.7

Point D (15.922MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	60.0	50.1
AV	50.0	38.3



EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ
Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

ZWS10B

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

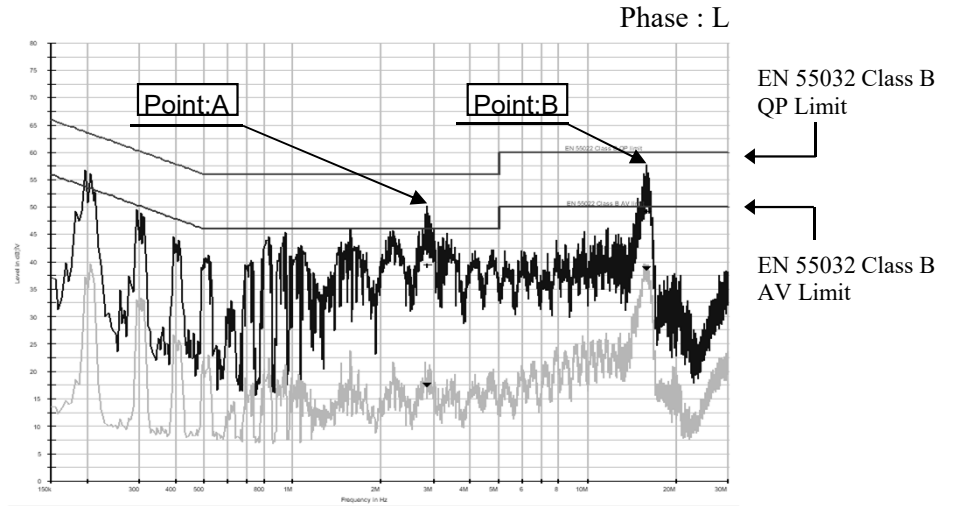
雑音端子電圧

Conducted Emission

24V

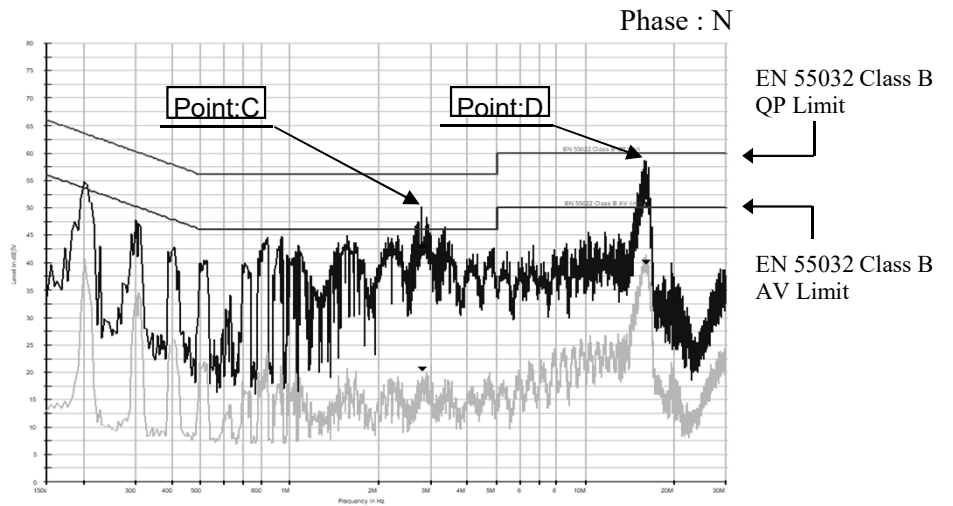
Point A (2.861MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	56.0	39.4
AV	46.0	17.5

Point B (15.866MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	60.0	49.3
AV	50.0	38.8



Point C (2.825MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	56.0	43.0
AV	46.0	20.5

Point D (16.004MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	60.0	50.8
AV	50.0	40.1



EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ
Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

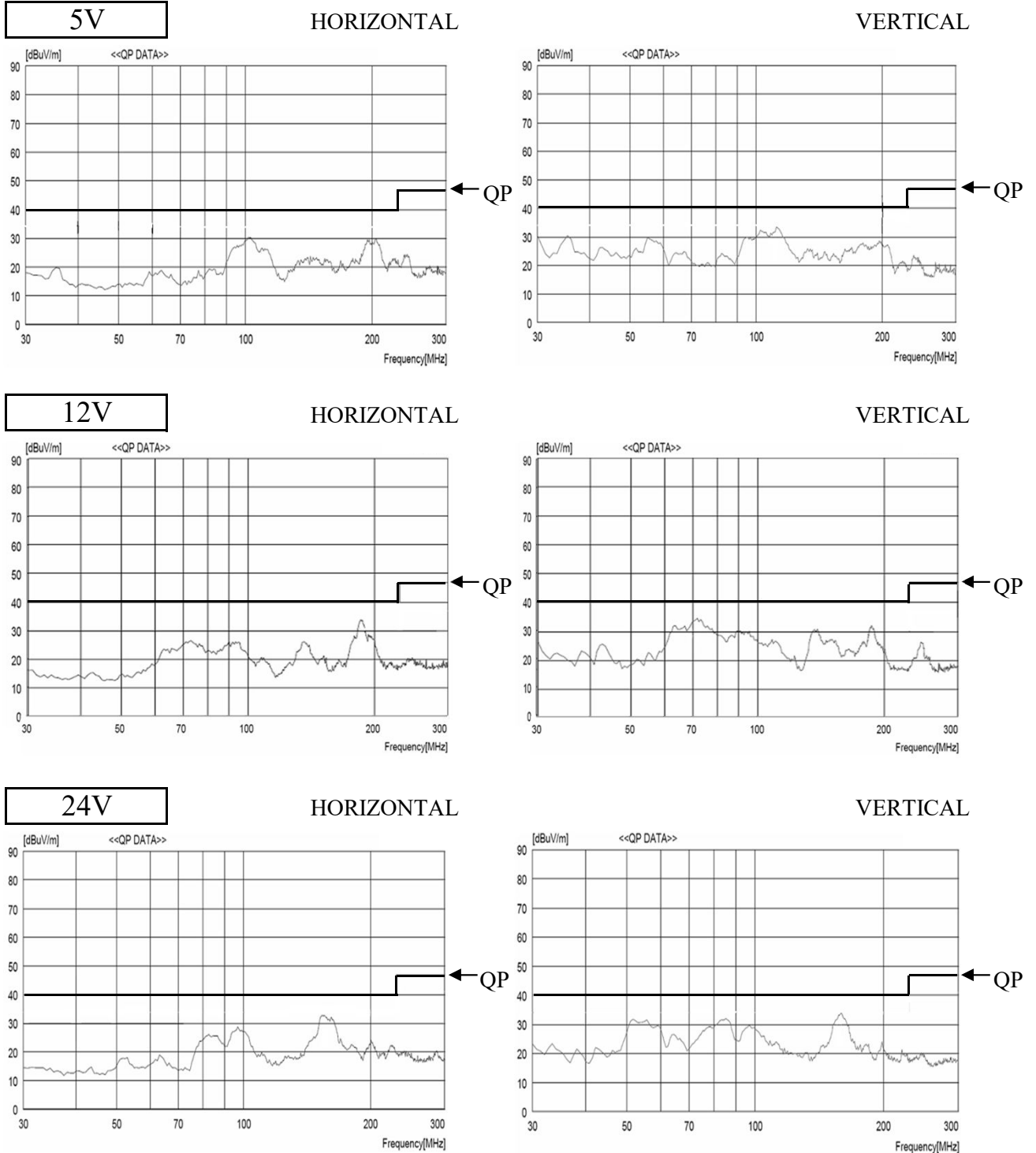
Electro-Magnetic Interference characteristics

ZWS10B

Conditions Vin : 230 VAC
Io : 100 %
Ta : 25 °C

雑音電界強度

Radiated Emission



EN55011-B,EN55032-Bの限界値はVCCI class Bの限界値と同じ
Limit of EN55011-B,EN55032-B are same as its VCCI class B.

表示はピーク値
Indication is peak values.